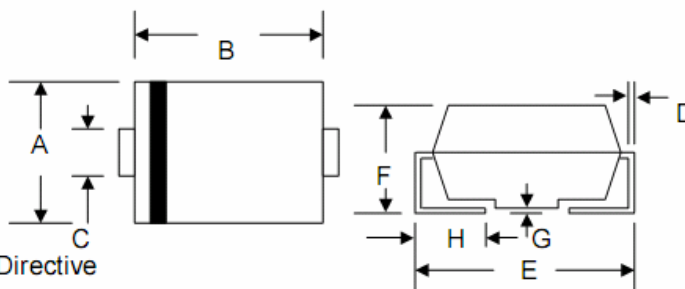


Features

- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- Surge Overload Rating to 50A Peak
- For Use in Low Voltage Application
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability
- Classification Rating 94V-0
- Green Products in Compliance with the RoHS Directive
- This is a Pb-Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

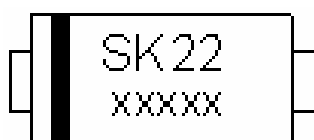


SMB/DO-214AA				
Dim	Min	Max	Min	Max
A	3.30	3.94	0.130	0.155
B	4.06	4.70	0.160	0.185
C	1.91	2.11	0.075	0.083
D	0.15	0.31	0.006	0.012
E	5.08	5.59	0.200	0.220
F	2.13	2.44	0.084	0.096
G	0.05	0.20	0.002	0.008
H	0.76	1.27	0.030	0.050
		In mm		In inch

Mechanical Data

- Case: Low Profile Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.093 grams (approx.)

Marking Diagram:



Where XXXXX is YYWWL

SK22 = Part Name
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
SK22-G-SK210-G	SMB (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.



Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Characteristic	Symbol	SK22-G	SK23-G	SK24-G	SK25-G	SK26-G	SK28-G	SK29-G	SK210-G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	VRRM VRWM VR	20	30	40	50	60	80	90	100	V
RMS Reverse Voltage	VR(RMS)	14	21	28	35	42	56	64	71	V
Average Rectified Output Current @TL = 105°C	Io	2.0								A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	50								A
Forward Voltage @IF = 2.0A	VFM	0.55			0.70		0.85			V
Peak Reverse Current @TA = 25°C At Rated DC Blocking Voltage @TA = 100°C	IRM	0.5 20								mA
Typical Thermal Resistance Junction to Ambient (Note 1)	RTHJA	75								°C/W
Operating Temperature Range	TJ	-65 to +125								°C
Storage Temperature Range	TSTG	-65 to +150								°C

Note: 1. Mounted on P.C. Board with 8.0mm² copper pad areas

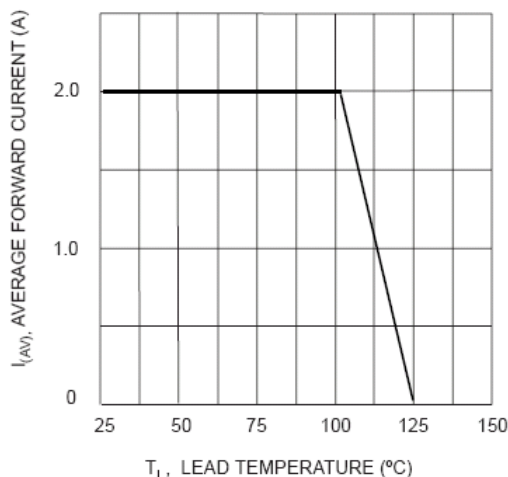


Fig. 1 Forward Current Derating Curve

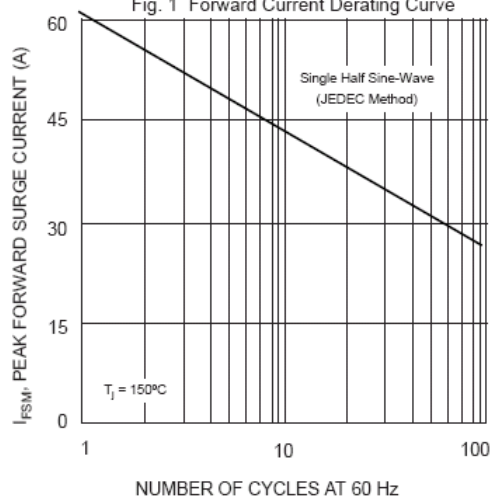


Fig. 3 Max Non-Repetitive Peak Fwd Surge Current

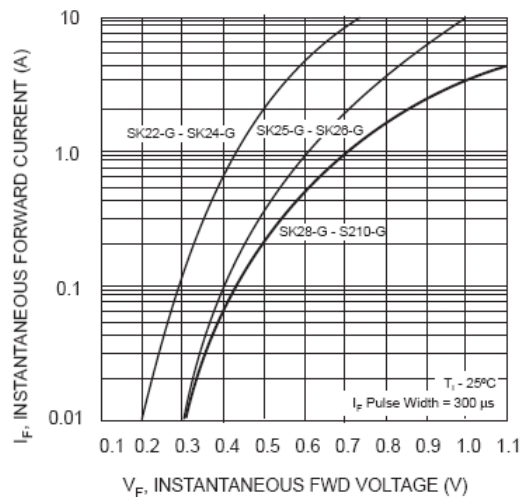


Fig. 2 Typ. Forward Characteristics

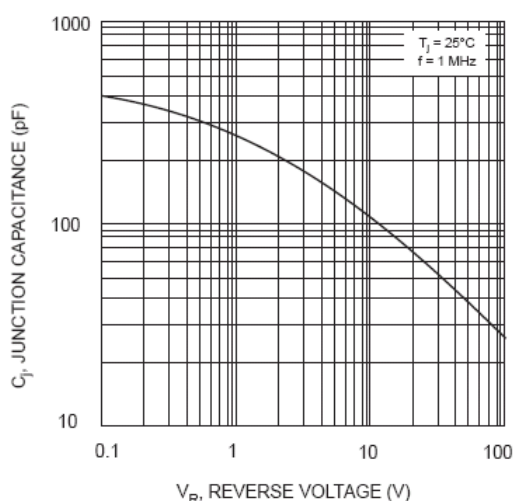


Fig. 4 Typical Junction Capacitance

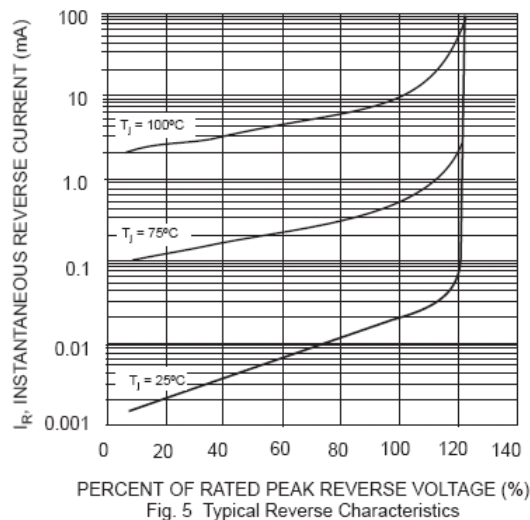


Fig. 5 Typical Reverse Characteristics



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